NSN 5961-01-028-6205

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-028-6205 **Inclosure Material:** Metal **Overall Length:** 1.375 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 150.0 forward voltage, peak and 225.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes forward current, total rms universal **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0